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INFORMATION DISCLOSURE STATEMENT BY APPLICANT Sheet 1 of 1		Filing Date : October 2, 2003
		First Named Inventor: Y. ABE
		Group Art Unit :
		Examiner Name :
		Attorney Docket No. : KAM 20.660

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No. ¹	U.S. Patent Document	Kind Code ² if known ²	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns Lines Where Relevant Passages or Relevant Figures Appear

FOREIGN DOCUMENTS

Examiner Initials	Cite No. ¹	Foreign Patent Document Office ³ Number ⁴ Kind Code ⁵ (if known)	Country	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YY/Y	Pages, Columns Lines Where Relevant Passages or Relevant Figures Appear
<i>m</i>		2004-043851	JP	Sumitomo Metal Mining Co Ltd	02-12-2004	
<i>m</i>		59-204625	JP	Daicel Chem Ind Ltd	11-20-1984	
<i>m</i>		9-209134	JP	Idemitsu Kosan Co Ltd	08-12-1997	
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<i>m</i>		2001-127336	JP	Natl Science Council of Roc	05-11-2001	

Other Prior Art-Non Patent Literature Documents

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), data, page(s), volume-issue number(s), publisher, country, where published, source.	Applicant check her if English language translation attached
<i>m</i>		JOHN L. VOSSSEN RF Sputtered Transparent Conductors The System In $\text{ZnO}_2\text{-SnO}_2$. RCA Laboratories, RCA Review Vol. 32 pgs 289-296, June 1971	
<i>m</i>		KATSUFUSA SHONO. Physics-Engineering Experiments. Semiconductor Technology First Volume. University of Tokyo Press May 17, 1976	
Examiner Signature	<i>Mark</i>	Date Considered	<i>5/5/07</i>

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